

Features

- ◆ 80W peak pulse power(8/20 μ s)
- ◆ Ultra low leakage: nA level
- ◆ Operating voltage: 5V
- ◆ Low clamping voltage
- ◆ Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
Air discharge: \pm 30kV
Contact discharge: \pm 30kV
 - IEC61000-4-4 (EFT) 40A (5/50ns)
 - IEC61000-4-5 (Lightning) 8A (8/20 μ s)
- ◆ RoHS Compliant

Mechanical Characteristics

- ◆ Package: SOT-23
- ◆ Lead Finish: Matte Tin
- ◆ Case Material: “Green” Molding Compound.
- ◆ UL Flammability Classification Rating 94V-0
- ◆ Moisture Sensitivity: Level 3 per J STD 020

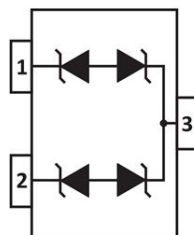
Applications

- ◆ Cellular Handsets and Accessories
- ◆ Notebooks and Handhelds
- ◆ Portable Instrumentation
- ◆ Set Top Box
- ◆ Industrial Controls

Ordering Information

Part Number	Qty per Reel	Reel Size
TPD5V0L2B3SO-7-F	3000	7"

Dimensions and Pin Configuration



Marking:TB2 Or V4t

Absolute Maximum Ratings (Tamb=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit
Peak Pulse Power (8/20μs)	Ppk	80	W
Peak Pulse Current (8/20μs)	Ipp	8	A
ESD per IEC 61000-4-2 (Air)	VESD	±30	kV
ESD per IEC 61000-4-2 (Contact)		±30	
Operating Temperature Range	TJ	-55 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C

Electrical Characteristics (TA=25°C unless otherwise specified)

Parameter	Symbol	Min	Typ	Max	Unit	Test Condition
Reverse Working Voltage	VRWM			5	V	
Breakdown Voltage	VBR	6		8.4	V	IT = 1mA
Reverse Leakage Current	IR			0.06	uA	VRWM = 5V
Clamping Voltage	VC		6		V	Ipp=1A(8x 20us pulse)
Clamping Voltage	VC			14	V	Ipp=8A (8x 20us pulse)
Junction Capacitance	CJ		15	20	pF	VR=0, f=1MHz, Pin 1 to Pin 3 or Pin 2 to Pin 3
Junction Capacitance	CJ		7		pF	VR=0, f=1MHz, Pin1 to Pin 2 or Pin 2 to Pin1

Typical Performance Characteristics ($T_A=25^\circ\text{C}$ unless otherwise Specified)

Fig1. 8/20 μs Pulse Waveform

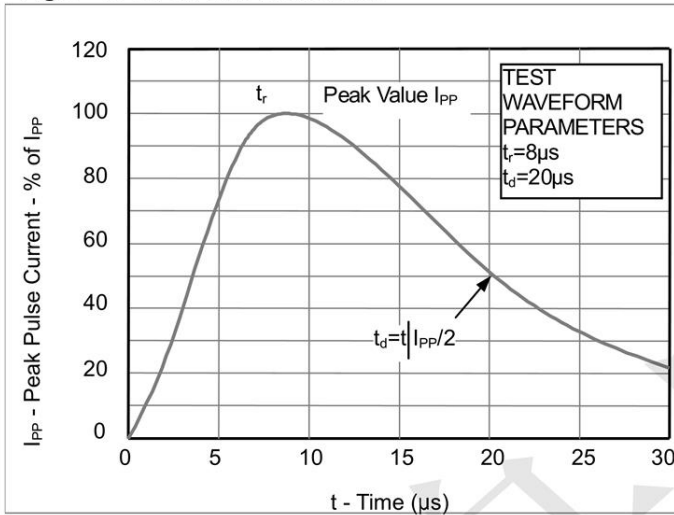


Fig2. ESD Pulse Waveform (according to IEC 61000-4-2)

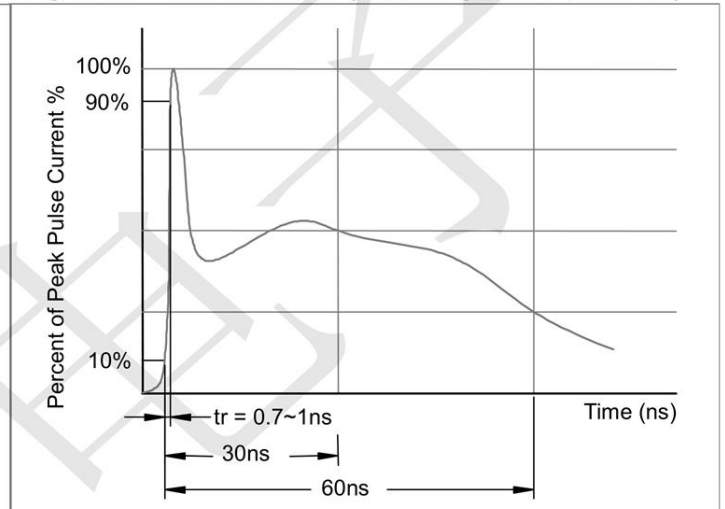
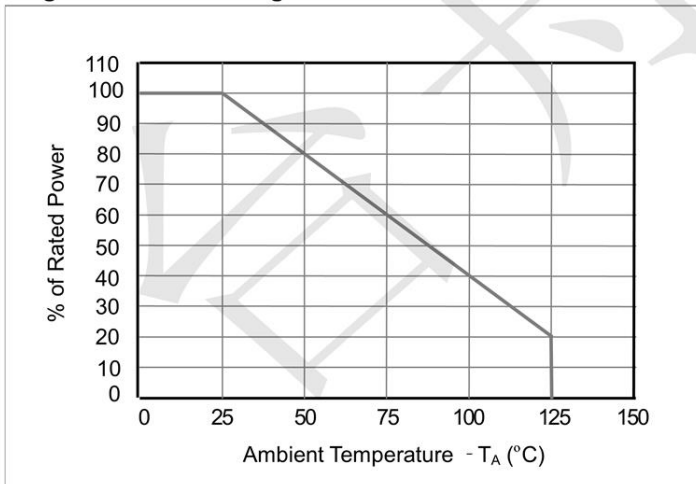
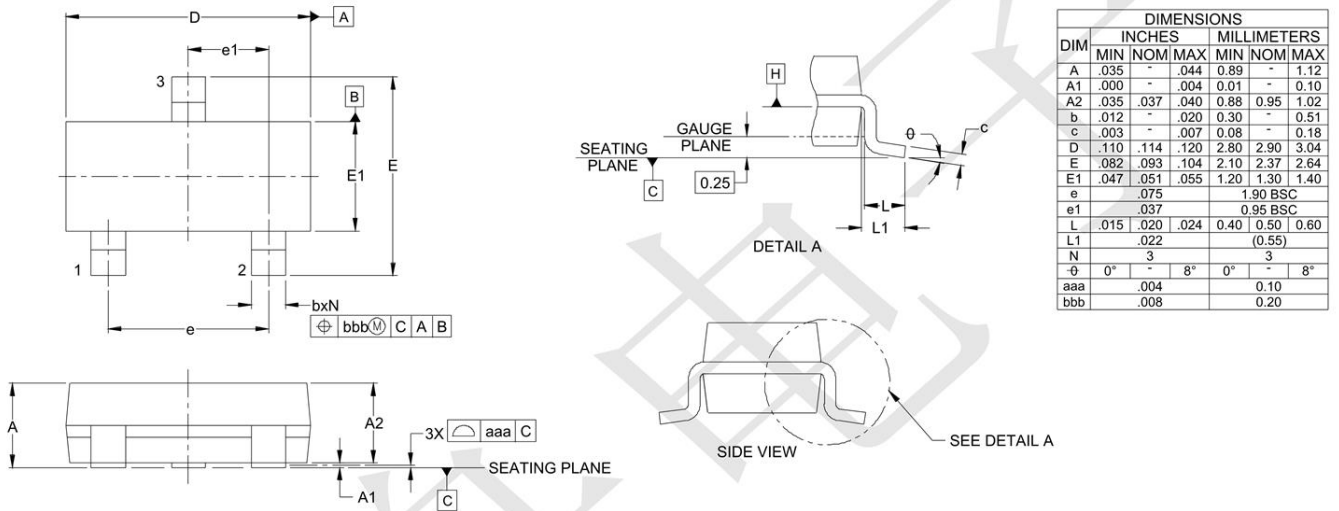


Fig3. Power Derating Curve



Outline Drawing - SOT23



Land Pattern - SOT23

